





50V NPN LOW SATURATION TRANSISTOR

Features

- BV_{CEO} > 50V
- I_C = 4A Continuous Collector Current
- Low Saturation Voltage (100mV max @1A)
- R_{SAT} = 68 mΩ for a Low Equivalent On-Resistance
- hFE Specified up to 6A for High Current Gain Hold Up
- Low Profile 0.6mm High Package for Thin Applications
- R_θJA Efficient, 60% Lower than SOT23
- 4mm² Footprint, 50% Smaller than SOT23
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: U-DFN2020-3 Type B
- Nominal Package Height: 0.6mm
- Case Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu, Solderable per MIL-STD-202, Method 208@4)
- Weight: 0.01 grams (Approximate)

Applications

- MOSFET Gate Driving
- DC-DC Converters
- Charging Circuits
- Motor Control
- Power Switches

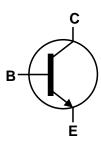
U-DFN2020-3 Type B



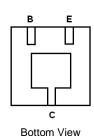




Bottom View



Device Symbol



Pin-Out

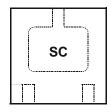
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN619MATA	SC	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



Top View

SC = Product Type Marking code





Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Parameter		Symbol	Limit	Unit		
Collector-Base Voltage		V_{CBO}	100			
Collector-Emitter Voltage		V _{CEO}	50			
Emitter-Base Voltage		V _{EBO}	7]		
Peak Pulse Current		I _{CM}	6			
Continuous Collector Current	(Note 5)	1-	4	۸		
Continuous Collector Current	(Note 6)	Ic	4.3	^		
Base Current		I _B	1			

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)		1.5 12	W	
Linear Derating Factor	(Note 6)	P _D	2.45 19.6	mW/°C	
Thermal Resistance, Junction to Ambient	(Note 5)	R _{0.JA} 83			
Thermal Resistance, Junction to Ambient	(Note 6)	$\kappa_{ heta}$ JA	51	°C/W	
Thermal Resistance, Junction to Lead	(Note 7)	$R_{ heta JL}$	16.8		
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C	

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

^{5.} For a device mounted with the exposed collector pad on 31mm x 31mm (10cm²) 1oz copper that is on a single sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state. The entire exposed collector pad is attached to the heatsink.

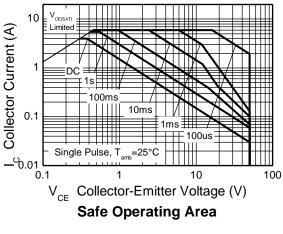
^{6.} Same as Note 5, except the device is measured at $t \le 5$ sec.

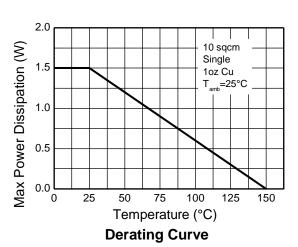
^{7.} Thermal resistance from junction to solder-point (on the exposed collector pad).

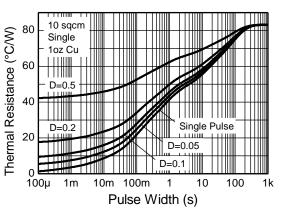
^{8.} Refer to JEDEC specification JESD22-A114 and JESD22-A115.

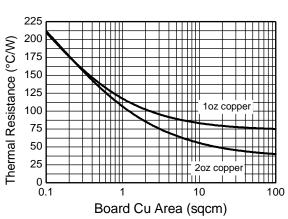


Thermal Characteristics and Derating Information



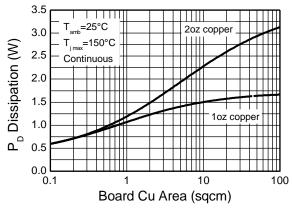






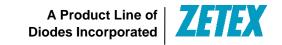
Transient Thermal Impedance





Power Dissipation v Board Area





Electrical Characteristics (@T_A = +25°C, unless otherwise specified)

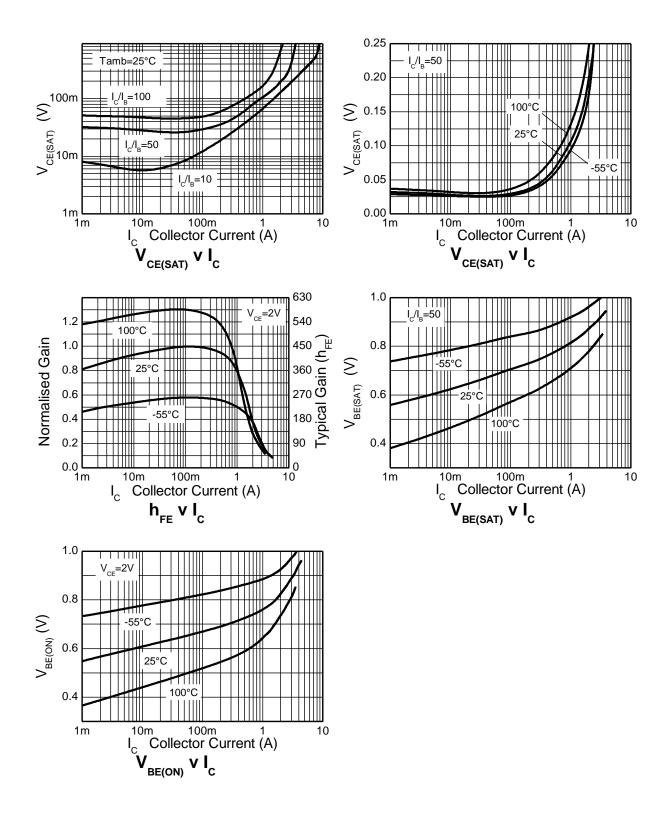
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	100	190	1	V	$I_C = 100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	50	65	-	V	I _C = 10 mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.2	-	V	I _E = 100 μA
Collector Cutoff Current	I _{CBO}	-	-	100	nA	V _{CB} = 80V
Emitter Cutoff Current	I _{EBO}	-	-	100	nA	V _{EB} = 6V
Collector Emitter Cutoff Current	I _{CES}	-	-	100	nA	V _{CES} = 40V
Static Forward Current Transfer Ratio (Note 9)	h _{FE}	200 300 200 100	400 450 400 225 40		-	$\begin{split} &I_{C} = 10\text{mA}, \ V_{CE} = 2\text{V} \\ &I_{C} = 200\text{mA}, \ V_{CE} = 2\text{V} \\ &I_{C} = 1\text{A}, \ V_{CE} = 2\text{V} \\ &I_{C} = 2\text{A}, \ V_{CE} = 2\text{V} \\ &I_{C} = 6\text{A}, \ V_{CE} = 2\text{V} \end{split}$
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)}	- - - -	10 70 145 115 225 270	20 100 200 220 300 320	mV	$I_C = 0.1A$, $I_B = 10mA$ $I_C = 1A$, $I_B = 50mA$ $I_C = 1A$, $I_B = 10mA$ $I_C = 2A$, $I_B = 50mA$ $I_C = 3A$, $I_B = 100mA$ $I_C = 4A$, $I_B = 200mA$
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	-	0.94	1.00	V	I _C = 4A, V _{CE} = 2V
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	-	1.00	1.07	V	I _C = 4A, I _B = 200mA
Output Capacitance	C _{obo}	-	12	20	pF	V _{CB} = 10V. f = 1MHz
Transition Frequency	f _T	100	165	-	MHz	V _{CE} = 10V, I _C = 50mA, f = 100MHz
Turn-On Time	t _{on}	-	170	-	ns	V _{CC} = 10V, I _C = 1A
Turn-Off Time	t _{off}	-	750	-	ns	$I_{B1} = I_{B2} = 10 \text{mA}$

Note: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.





Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

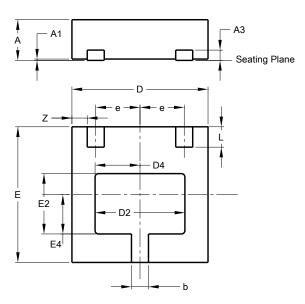




Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

U-DFN2020-3 (Type B)

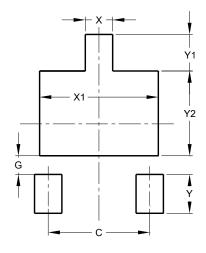


U-DFN2020-3 (Type B)					
Dim	Min	Max	Тур		
Α	0.57	0.63	0.60		
A1	0.00	0.05	0.02		
A3	_		0.152		
b	0.20	0.30	0.25		
D	1.950	2.075	2.00		
D2	1.22	1.42	1.32		
D4	0.56	0.76	0.66		
Е	1.950	2.075	2.00		
E2	0.79	0.99	0.89		
E4	0.48	0.68	0.58		
е	_	_	0.65		
L	0.25	0.35	0.30		
Z		_	0.225		
All Dimensions in mm					

Suggested Pad Layout

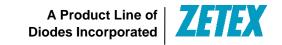
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

U-DFN2020-3 (Type B)



Dimensions	Value (in mm)		
С	1.300		
G	0.240		
Х	0.350		
X1	1.520		
Υ	0.500		
Y1	0.470		
Y2	1 090		





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